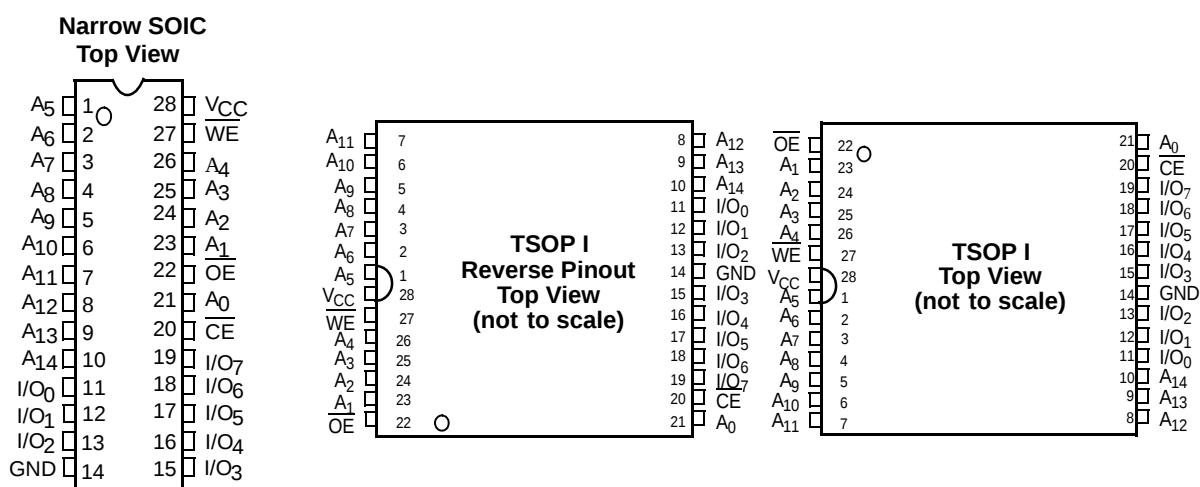


Product Portfolio

Product	Range	V _{CC} Range (V)			Speed (ns)	Power Dissipation			
						Operating, I _{CC} (mA)		Standby, I _{SB2} (μA)	
		Min.	Typ. ^[2]	Max.		Typ. ^[2]	Max.	Typ. ^[2]	Max.
CY62256VLL	Com'l/Ind'l	2.7	3.0	3.6	70	11	30	0.1	5
	Automotive								130

Pin Configurations



Pin Definitions

Pin Number	Type	Description
1–10, 21, 23–26	Input	A ₀ –A ₁₄ . Address Inputs
11–13, 15–19	Input/Output	I/O ₀ –I/O ₇ . Data lines. Used as input or output lines depending on operation
27	Input/Control	$\overline{\text{WE}}$. When selected LOW, a WRITE is conducted. When selected HIGH, a READ is conducted
20	Input/Control	$\overline{\text{CE}}$. When LOW, selects the chip. When HIGH, deselects the chip
22	Input/Control	$\overline{\text{OE}}$. Output Enable. Controls the direction of the I/O pins. When LOW, the I/O pins behave as outputs. When deasserted HIGH, I/O pins are Tri-stated, and act as input data pins
14	Ground	GND. Ground for the device
28	Power Supply	V _{CC} . Power supply for the device

Note:

2. Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at V_{CC} = V_{CC(typ.)}, T_A = 25°C, and t_{AA} = 70 ns.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature –65°C to +150°C

Ambient Temperature with
Power Applied..... –55°C to +125°C

Supply Voltage to Ground Potential
(Pin 28 to Pin 14) –0.5V to +4.6V

DC Voltage Applied to Outputs
in High-Z State^[3] –0.5V to $V_{CC} + 0.5V$

DC Input Voltage^[3] –0.5V to $V_{CC} + 0.5V$

Output Current into Outputs (LOW) 20 mA

Static Discharge Voltage..... > 2001V
(per MIL-STD-883, Method 3015)

Latch-up Current..... > 200 mA

Operating Range

Device	Range	Ambient Temperature (T_A) ^[4]	V_{CC}
CY62256V	Commercial	0°C to +70°C	2.7V to 3.6V
	Industrial	–40°C to +85°C	
	Automotive	–40°C to +125°C	

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions	CY62256V-70			Unit
			Min.	Typ. ^[2]	Max.	
V_{OH}	Output HIGH Voltage	$I_{OH} = -1.0 \text{ mA}$, $V_{CC} = 2.7V$	2.4			V
V_{OL}	Output LOW Voltage	$I_{OL} = 2.1 \text{ mA}$, $V_{CC} = 2.7V$			0.4	V
V_{IH}	Input HIGH Voltage		2.2		$V_{CC} + 0.3V$	V
V_{IL}	Input LOW Voltage		–0.5		0.8	V
I_{IX}	Input Leakage Current	$GND \leq V_{IN} \leq V_{CC}$	Com'l, Ind'l	–1	+1	μA
			Automotive	–10	+10	μA
I_{OZ}	Output Leakage Current	$GND \leq V_{IN} \leq V_{CC}$, Output Disabled	Com'l, Ind'l	–1	+1	μA
			Automotive	–10	+10	μA
I_{CC}	V_{CC} Operating Supply Current	$V_{CC} = 3.6V$, $I_{OUT} = 0 \text{ mA}$, $f = f_{Max} = 1/t_{RC}$	All ranges	11	30	mA
I_{SB1}	Automatic CE Power-down Current— TTL Inputs	$V_{CC} = 3.6V$, $\overline{CE} \geq V_{IH}$, $V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$, $f = f_{Max}$	All ranges	100	300	μA
I_{SB2}	Automatic CE Power-down Current— CMOS Inputs	$V_{CC} = 3.6V$, $\overline{CE} \geq V_{CC} - 0.3V$, $V_{IN} \geq V_{CC} - 0.3V$ or $V_{IN} \leq 0.3V$, $f = 0$	Com'l	0.1	5	μA
			Ind'l	0.1	10	
			Automotive	0.1	130	

Notes:

3. V_{IL} (min.) = –2.0V for pulse durations of less than 20 ns.

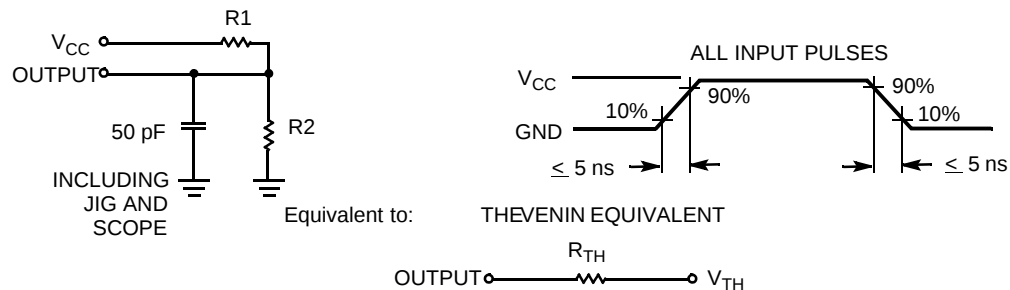
4. T_A is the "Instant-On" case temperature.

Capacitance^[5]

Parameter	Description	Test Conditions	Max.	Unit
C _{IN}	Input Capacitance	T _A = 25°C, f = 1 MHz, V _{CC} = V _{CC(typ.)}	6	pF
C _{OUT}	Output Capacitance		8	pF

Thermal Resistance

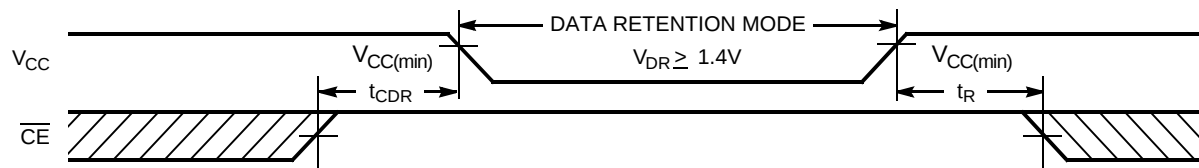
Parameter	Description	Test Conditions	SOIC	TSOPI	RTSOPI	Unit
Θ _{JA}	Thermal Resistance (Junction to Ambient) ^[6]	Still Air, soldered on a 3 × 4.5 inch, 2-layer printed circuit board	68.45	87.62	87.62	°C/W
Θ _{JC}	Thermal Resistance (Junction to Case) ^[5]		26.94	23.73	23.73	°C/W

AC Test Loads and Waveforms


Parameter	3.3V	Units
R1	1100	Ohms
R2	1500	Ohms
R _{TH}	645	Ohms
V _{TH}	1.750	Volts

Data Retention Characteristics (Over the Operating Range)

Parameter	Description	Conditions ^[6]	Min.	Typ. ^[2]	Max.	Unit
V _{DR}	V _{CC} for Data Retention		1.4			V
I _{CCDR}	Data Retention Current	V _{CC} = 1.4V, $\overline{CE} \geq V_{CC} - 0.3V$, V _{IN} ≥ V _{CC} - 0.3V or V _{IN} ≤ 0.3V	Com'l	0.1	3	μA
			Ind'l	0.1	6	
			Auto	0.1	50	
t _{CDR} ^[6]	Chip Deselect to Data Retention Time		0			ns
t _R ^[6]	Operation Recovery Time		t _{RC}			ns

Data Retention Waveform

Notes:

5. Tested initially and after any design or process changes that may affect these parameters.
 6. No input may exceed V_{CC} + 0.3V.

Switching Characteristics Over the Operating Range^[7]

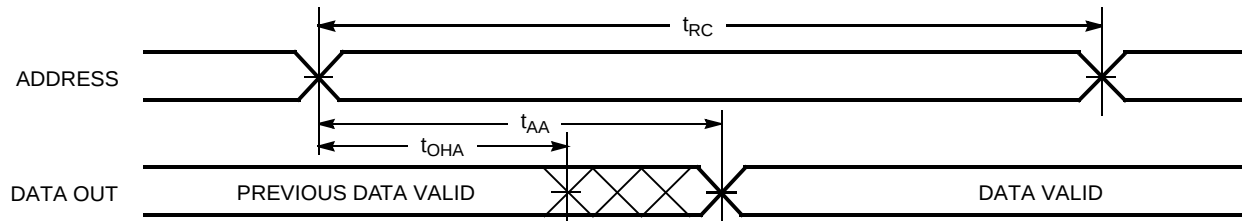
Parameter	Description	CY62256V-70		Unit
		Min.	Max.	
Read Cycle				
t _{RC}	Read Cycle Time	70		ns
t _{AA}	Address to Data Valid		70	ns
t _{OHA}	Data Hold from Address Change	10		ns
t _{ACE}	$\overline{CE}$ LOW to Data Valid		70	ns
t _{DOE}	$\overline{OE}$ LOW to Data Valid		35	ns
t _{LZOE}	$\overline{OE}$ LOW to Low-Z ^[8]	5		ns
t _{HZOE}	$\overline{OE}$ HIGH to High-Z ^[8, 9]		25	ns
t _{LZCE}	$\overline{CE}$ LOW to Low-Z ^[8]	10		ns
t _{HZCE}	$\overline{CE}$ HIGH to High-Z ^[8, 9]		25	ns
t _{PU}	$\overline{CE}$ LOW to Power-up	0		ns
t _{PD}	$\overline{CE}$ HIGH to Power-down		70	ns
Write Cycle ^[10, 11]				
t _{WC}	Write Cycle Time	70		ns
t _{SCE}	$\overline{CE}$ LOW to Write End	60		ns
t _{AW}	Address Set-up to Write End	60		ns
t _{HA}	Address Hold from Write End	0		ns
t _{SA}	Address Set-up to Write Start	0		ns
t _{PWE}	$\overline{WE}$ Pulse Width	50		ns
t _{SD}	Data Set-up to Write End	30		ns
t _{HD}	Data Hold from Write End	0		ns
t _{HZWE}	$\overline{WE}$ LOW to High-Z ^[8, 9]		25	ns
t _{LZWE}	$\overline{WE}$ HIGH to Low-Z ^[8]	10		ns

Notes:

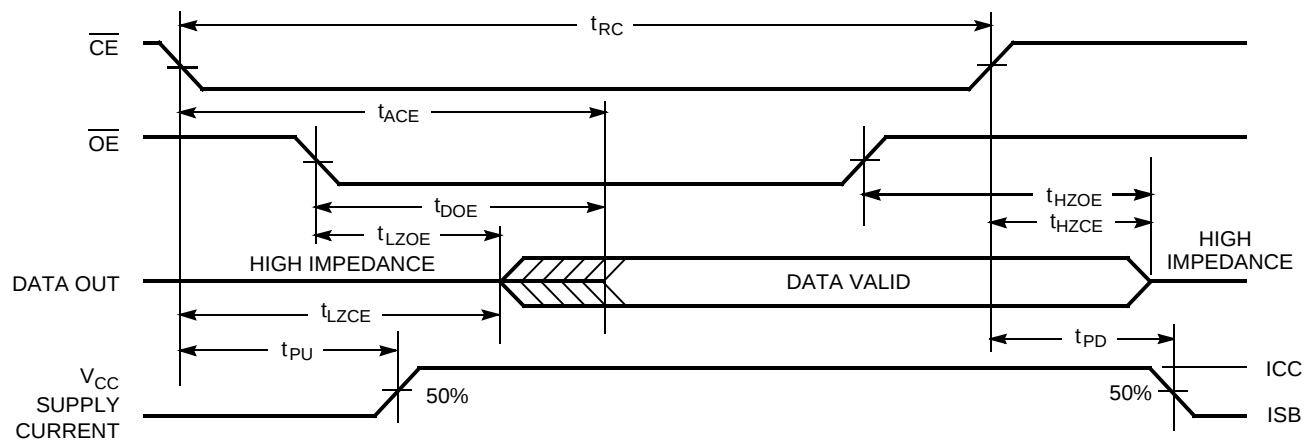
7. Test conditions assume signal transition time of 5 ns or less timing reference levels of $V_{CC}/2$, input pulse levels of 0 to V_{CC} , and output loading of the specified I_{OL}/I_{OH} and 50 pF load capacitance.
8. At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any given device.
9. t_{HZOE} , t_{HZCE} , and t_{HZWE} are specified with $C_L = 5$ pF as in (b) of AC Test Loads. Transition is measured ± 200 mV from steady-state voltage.
10. The internal write time of the memory is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
11. The minimum write cycle time for write cycle #3 ($\overline{WE}$ controlled, $\overline{OE}$ LOW) is the sum of t_{HZWE} and t_{SD} .

Switching Waveforms

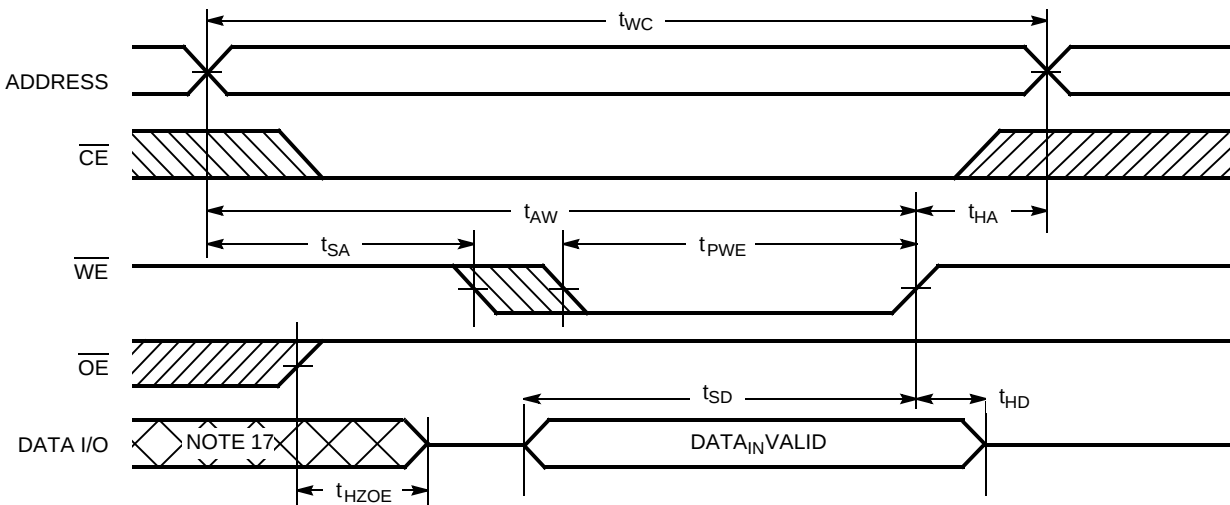
Read Cycle No. 1 (Address Transition Controlled)^[12, 13]



Read Cycle No. 2 ($\overline{\text{OE}}$ Controlled)^[13, 14]



Write Cycle No. 1 ($\overline{\text{WE}}$ Controlled)^[10, 15, 16]

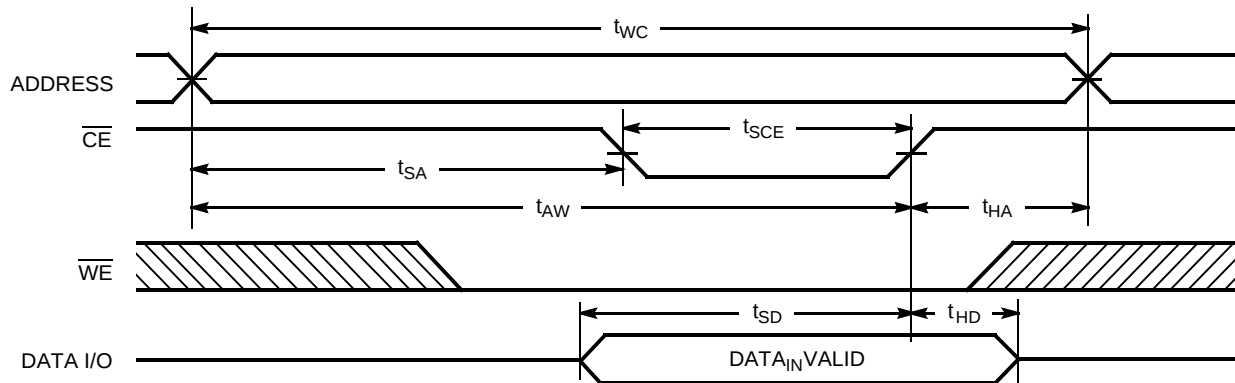


Notes:

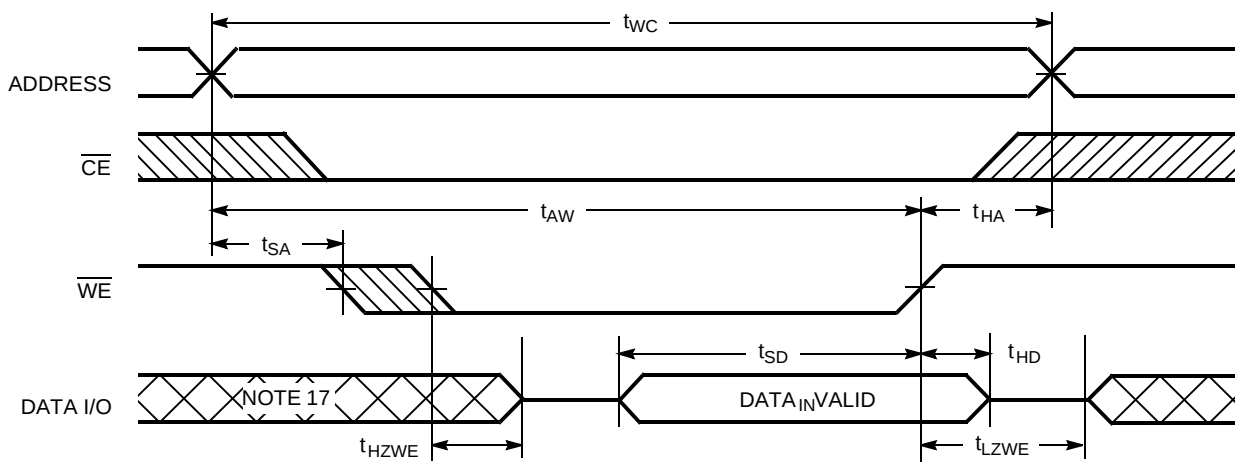
12. Device is continuously selected. $\overline{\text{OE}}, \overline{\text{CE}} = V_{\text{IL}}$.
13. $\overline{\text{WE}}$ is HIGH for read cycle.
14. Address valid prior to or coincident with $\overline{\text{CE}}$ transition LOW.
15. Data I/O is high impedance if $\overline{\text{OE}} = V_{\text{IH}}$.
16. If CE goes HIGH simultaneously with WE HIGH, the output remains in a high-impedance state.
17. During this period, the I/Os are in output state and input signals should not be applied.

Switching Waveforms (continued)

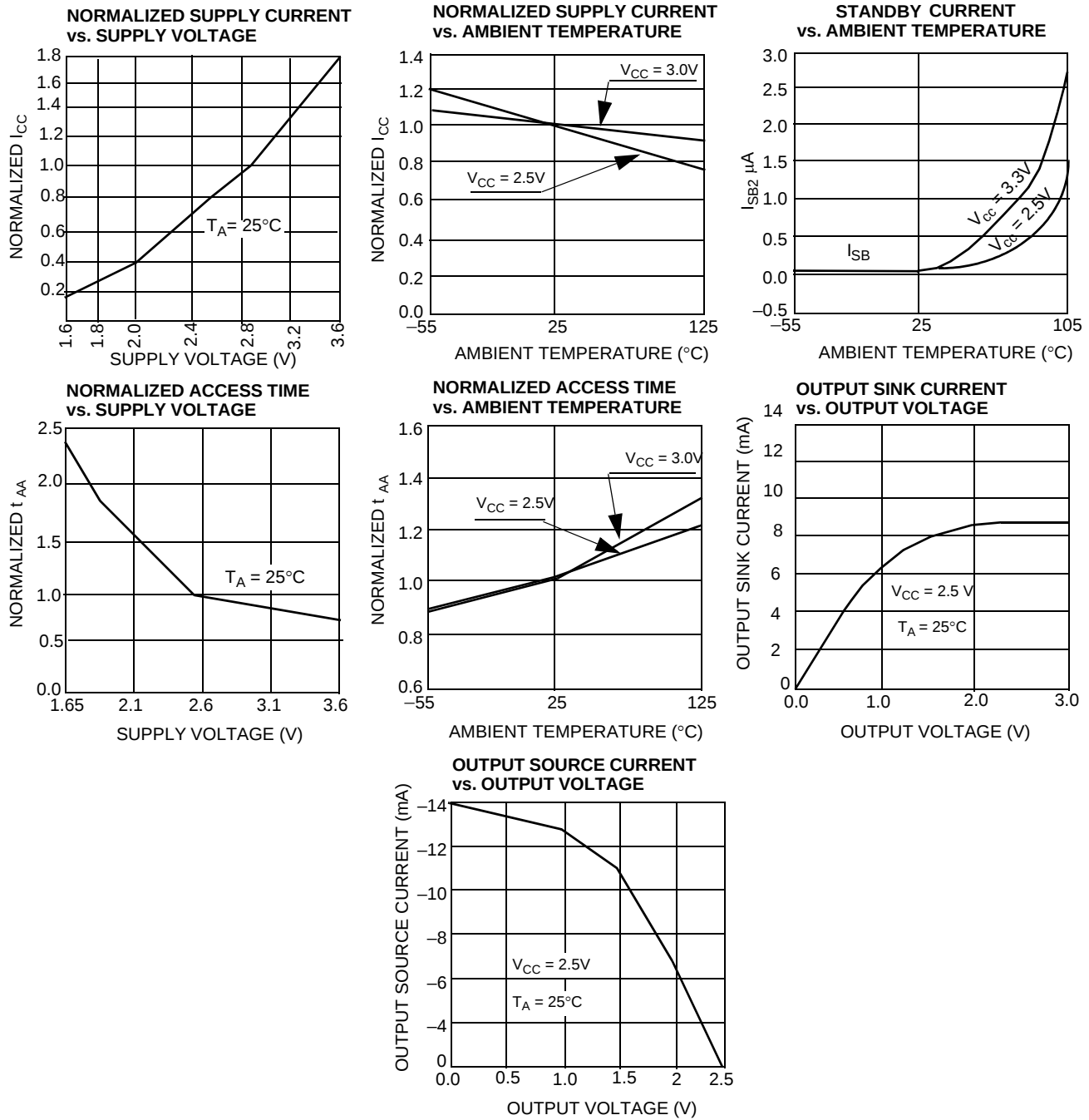
Write Cycle No. 2 ($\overline{\text{CE}}$ Controlled)^[10, 15, 16]



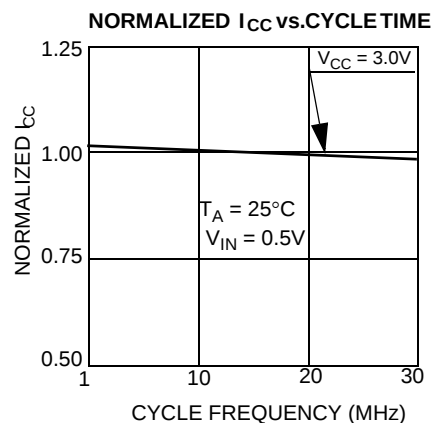
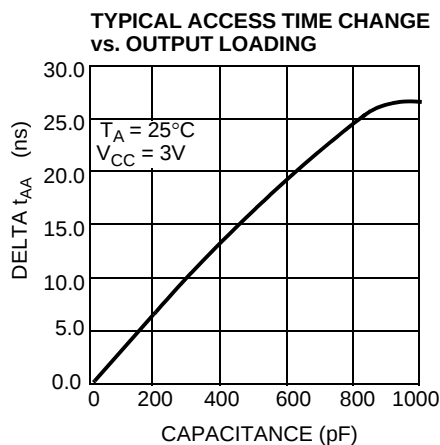
Write Cycle No. 3 ($\overline{\text{WE}}$ Controlled, $\overline{\text{OE}}$ LOW)^[11, 16]



Typical DC and AC Characteristics



Typical DC and AC Characteristics (continued)



Truth Table

$\overline{\text{CE}}$	$\overline{\text{WE}}$	$\overline{\text{OE}}$	Inputs/Outputs	Mode	Power
H	X	X	High-Z	Deselect/Power-down	Standby (I_{SB})
L	H	L	Data Out	Read	Active (I_{CC})
L	L	X	Data In	Write	Active (I_{CC})
L	H	H	High-Z	Deselect, Output Disabled	Active (I_{CC})

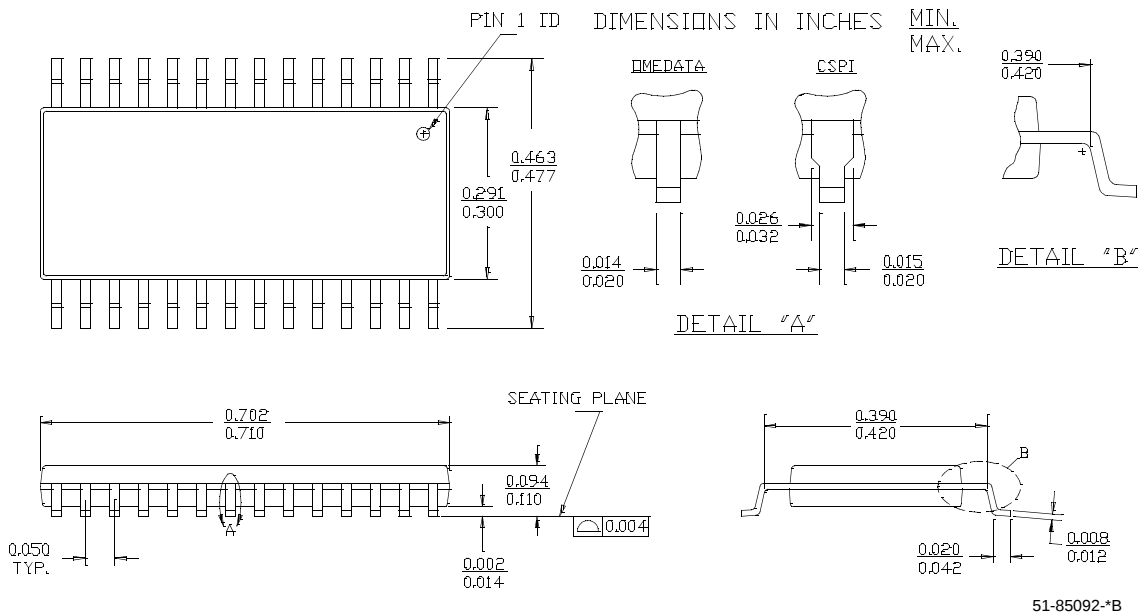
Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
70	CY62256VLL-70SNC	51-85092	28-pin (300-mil Narrow Body) SNC	Commercial
	CY62256VLL-70SNXC		28-pin (300-mil Narrow Body) SNC (Pb-Free)	
	CY62256VLL-70ZC	51-85071	28-pin TSOP I	
	CY62256VLL-70ZXC		28-pin TSOP I (Pb-Free)	
	CY62256VLL-70SNXI	51-85092	28-pin (300-mil Narrow Body) SNC (Pb-Free)	Industrial
	CY62256VLL-70ZI	51-85071	28-pin TSOP I	
	CY62256VLL-70ZXI		28-pin TSOP I (Pb-Free)	
	CY62256VLL-70ZRI	51-85074	28-pin Reverse TSOP I	
	CY62256VLL-70ZRXI		28-pin Reverse TSOP I (Pb-Free)	
	CY62256VLL-70SNE	51-85092	28-pin (300-mil Narrow Body) SNC	Automotive
	CY62256VLL-70SNXE		28-pin (300-mil Narrow Body) SNC (Pb-Free)	
	CY62256VLL-70ZE	51-85071	28-pin TSOP I	
	CY62256VLL-70ZXE		28-pin TSOP I (Pb-Free)	
	CY62256VLL-70ZRE	51-85074	28-pin Reverse TSOP I	
	CY62256VLL-70ZRXE		28-pin Reverse TSOP I (Pb-Free)	

Please contact your local Cypress sales representative for availability of these parts

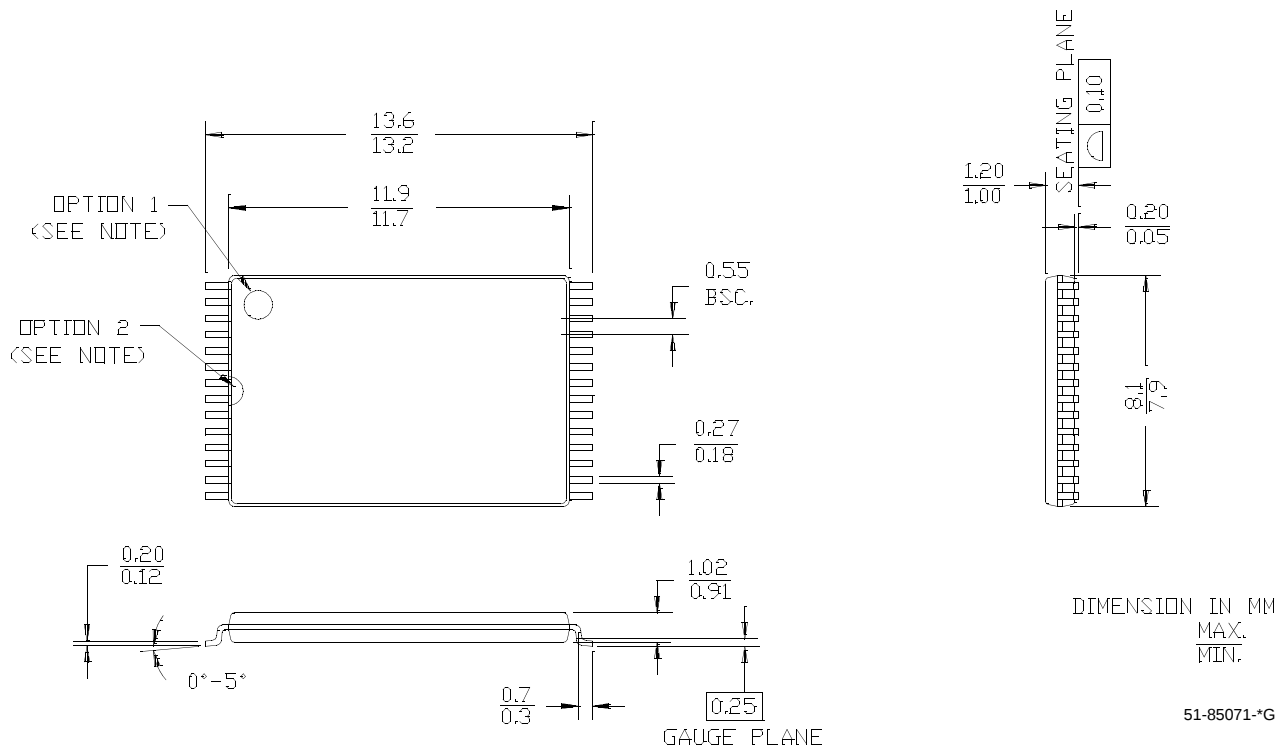
Package Diagrams

28-pin (300-mil) SNC (Narrow Body) (51-85092)



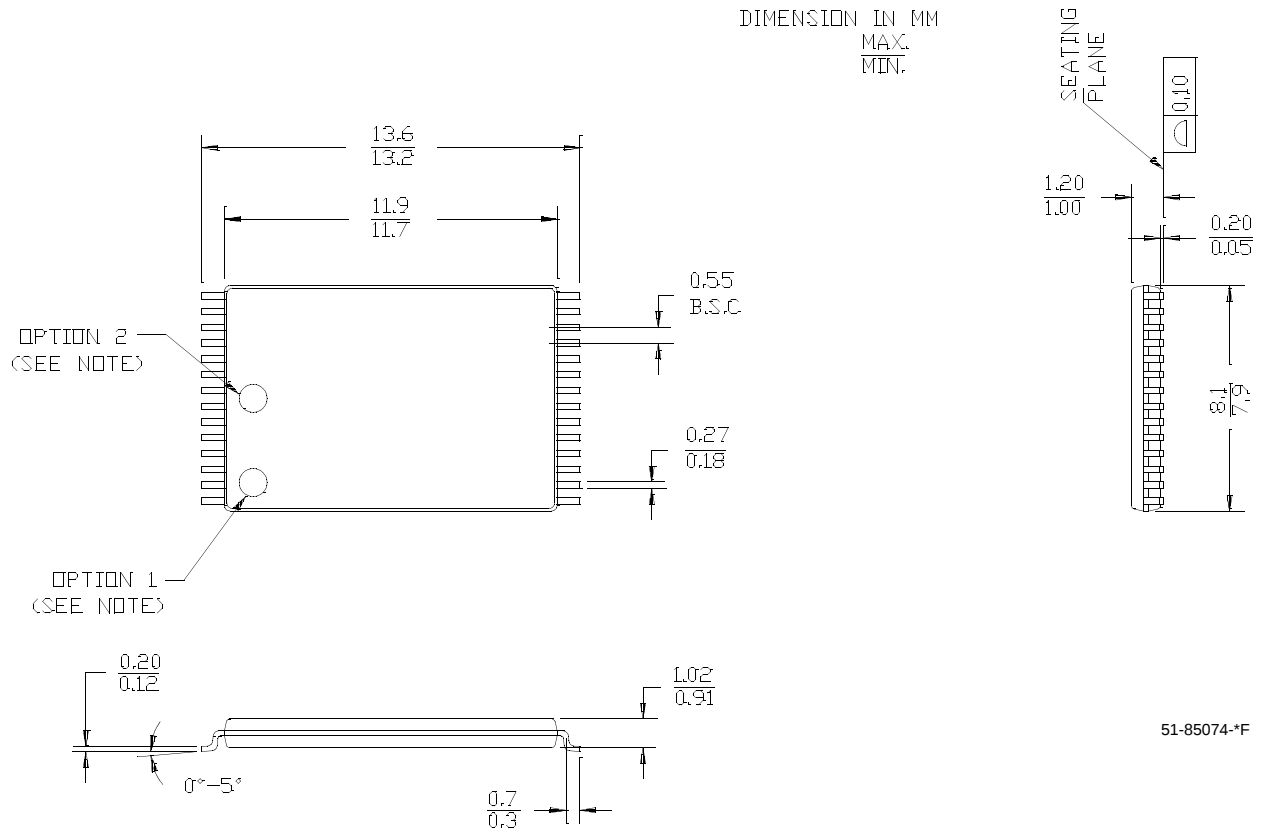
28-pin Thin Small Outline Package Type 1 (8 × 13.4 mm) (51-85071)

NOTE: ORIENTATION I.D. MAY BE LOCATED EITHER AS SHOWN IN OPTION 1 OR OPTION 2



Package Diagrams (continued)
28-pin Reverse Thin Small Outline Package Type 1 (8 × 13.4 mm) (51-85074)

NOTE: ORIENTATION I.D. MAY BE LOCATED EITHER
AS SHOWN IN OPTION 1 OR OPTION 2



All product and company names mentioned in this document are the trademarks of their respective holders.

Document History Page

Document Title: CY62256V, 256K (32K x 8) Static RAM Document Number: 38-05057				
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	107248	09/10/01	SZV	Changed from spec number: 38-00519 to 38-05057
*A	111445	11/01/01	MGN	Removed obsolete parts. Change to standard format
*B	115229	05/23/02	GBI	Changed SN package diagram
*C	116507	09/04/02	GBI	Added footnote 1 Clarified I_{CC} spec for $V_{CC(typ)} = 2.5V$
*D	239134	See ECN	AJU	Added Automotive product information
*E	344595	See ECN	SYT	Added Pb-Free packages on page# 10
*F	493277	See ECN	VKN	Changed address of Cypress Semiconductor Corporation on Page# 1 from "3901 North First Street" to "198 Champion Court" Removed part # CY62256V25LL from the product offering Updated Ordering Information Table